



THE DATASHEET OF FZT4403TA



**SOT223 PNP SILICON PLAIN
SWITCHING TRANSISTOR**
ISSUE 4 – JUNE 1996 

PARTMARKING DETAIL – FZT4403

ABSOLUTE MAXIMUM RATINGS

PARAMETER
Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation at $T_{amb}=25^{\circ}\text{C}$
Operating and Storage Temperature Range



ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$
Emitter Base Breakdown Voltage	$V_{(BR)EBO}$
Base Cut-off Current	I_{BEX}
Collector-Emitter Cut-off Current	I_{CEX}
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$
Static Forward Current Transfer Ratio	h_{FE}
Transition Frequency	f_T
Output Capacitance	C_{ob0}
Input Capacitance	C_{ibo}

*Measured under pulsed conditions. Puls

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